



11/9/2007

RELIABILITY REPORT
FOR

DS1124, Rev A2, Aging Qualification

Maxim Integrated Products

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products and processes:

DS1124, Rev A2, Aging Qualification

Device Description:

A description of the device used in this qualification can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10⁻⁵ eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process/assembly is:

FAILURE RATE:	MTTF (YRS):	7932	FITS:	14.4
	DEVICE HOURS:	67500	FAILS:	0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60%	Ea: 0.7	B: 0	Tu: 25 °C	Vu: 5.5 Volts
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The reliability data follows. At the start of this data is the device information. This is a description of the device for this report. Following this is the assembly information. This section includes a description of the assembly vehicle used to generate this reliability data for both qualifications and monitors. The next section is the detailed reliability data for each stress found in the qualification / monitor. If there are additional assemblies used as part of this report, a description of each will follow which includes the respective reliability data for that assembly. The reliability data section includes the latest data available.

Device Information:

Device:	DS1124
Process:	E6WA-2P2M,HPVt,E2,EPROGVt,TCZ,PF ALOCOS:GOI
Passivation:	Passivation w/Nov TEOS Oxide-Nitride
Die Size:	61 x 74
Number of Transistors:	1
Interconnect:	Aluminum / 0.5% Copper
Gate Oxide Thickness:	150 Å

Assembly Information:

Qualification Vehicle:	DS1124
Assembly Site:	ATP (Amkor, PI)
Pin Count:	10
Package Type:	uSOP (Pb-Free)
Body Size:	3x0.85
Mold Compound:	Sumitomo G700K
Lead Frame:	Stamped Copper CDA194
Lead Finsh:	Sn Plate 100% Matte (With Anneal Bake)
Die Attach:	8290 Ablestik
Bond Wire / Size:	Au / 1.3 mil
Theta JA:	180
Theta JC:	41.9
Flammability:	UL 94-V0
Moisture Sensitivity (JEDEC J-STD20A)	Level 1
Date Code Range:	0718 to 0718

DATE CODE: 0718 **LOT NUMBER:** QD730629AA-NPI

ELECTRICAL CHARACTERIZATION

DESCRIPTION	DATE CODE CONDITION	READPOINT	QTY FAILS	FA#
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